



FIRST-YEAR OF MASTER OF SCIENCE PHYSICS REVISED SYLLABUS ACCORDING TO CBCS NEP2020

**COURSE TITLE:-Physics of semiconductor diode and transistor
SEMESTER-II
W.E.F. 2023-2024**

**RECOMMENDED BY THE BOARD OF STUDIES IN PHYSICS
AND
APPROVED BY THE ACADEMIC COUNCIL**

Devrukh Shikshan Prasarak Mandal's

Nya. Tatyasaheb Athalye Arts, Ved. S. R. Sapre Commerce, and
Vid. Dadasaheb Pitre Science College (Autonomous), Devrukh.
Tal.Sanameshwar, Dist. Ratnagiri-415804, Maharashtra, India

Academic Council Item No: **03 dated 8 July 2023**

Name of the Implementing Institute	:	Nya. Tatyasaheb Athalye Arts, Ved. S. R. Sapre Commerce, and Vid. Dadasaheb Pitre Science College (Autonomous), Devrukh. Tal. Sangmeshwar, Dist. Ratnagiri-415804,
Name of the Parent University	:	University of Mumbai
Name of the Programme	:	Master of Science
Name of the Department	:	Physics
Name of the Class	:	First Year
Semester	:	Second
No. of Credits	:	02
Title of the Course	:	Physics of Semiconductordiodes and Transistors
Course Code	:	S514PHT
Name of the Vertical in adherence to NEP 2020	:	Elective
Eligibility for Admission	:	BSc in Physics
Passing Marks	:	40%
Mode of Assessment	:	Formative and Summative
Level	:	PG
Pattern of Marks Distribution for TE and CIA	:	60:40
Status	:	NEP-CBCS
To be implemented from Academic Year	:	2023-2024
Ordinances /Regulations (if any)		

Syllabus for First Year of Master of Science in Physics

(With effect from the academic year 2023-2024)

SEMESTER - II

Course Title: Physics of Semiconductor diodes and Transistors No. of Credits - 02

Type of Vertical: Elective

COURSE CODE: S514PHT

Learning Outcomes Based on BLOOM's Taxonomy:

After completing the course, the learner will be able to...

Course Learning Outcome No.	Blooms Taxonomy	Course Learning Outcome
CLO-01	Remember	Recall the basics of semiconductors and devices
CLO-02	Understand	Understand the classification of semiconductors and carrier transport phenomenon
CLO-03	Analyze	Explain the fabrication of various semiconductor devices
CLO-04	Understand	Understand the working of devices like MESFET, MODFET etc

Syllabus for First Year of Master of Science in Physics**(With effect from the academic year 2023-2024)****SEMESTER - II****Paper No–Physics–V****Course Title: Physics of Semiconductor diodes and Transistors No. of Credits - 02****Type of Vertical: Elective****COURSE CODE: S514PHT**

COURSE CONTENT			
Module No.	Content	Credits	No. of Lectures
1	<i>Semiconductor Physics:</i> Classification of Semiconductors; Crystal structure with examples of Si, Ge & GaAs semiconductors; Energy band structure of Si, Ge & GaAs; Extrinsic and compensated Semiconductors; Temperature dependence of Fermi-energy and carrier concentration. Drift, diffusion and injection of carriers; Carrier generation and recombination processes-Direct recombination, Indirect recombination, Surface recombination, Auger recombination; Applications of continuity equation-Steady state injection from one side, Minority carriers at surface, Haynes Shockley experiment, High field effects. Hall Effect; Four – point probe resistivity measurement; Carrier life time measurement by light pulse technique.	01	15
2	<i>Semiconductor Devices I:</i> p-n junction : Fabrication of p-n junction by diffusion and ion-implantation; Abrupt and linearly graded junctions; Thermal equilibrium conditions; Depletion regions; Depletion capacitance, Capacitance – voltage (C-V) characteristics, Evaluation of impurity distribution, Varactor; Ideal and Practical Current-voltage (I-V) characteristics; Tunneling and avalanche reverse junction break down mechanisms; Minority carrier storage, diffusion capacitance, transient behavior; Ideality factor and carrier concentration measurements; Carrier life time measurement by reverse recovery of junction diode;; p-i-n diode; Tunnel diode, Introduction to p-n junction solar cell and semiconductor laser diode.	01	15
	Total	02	30

Main References:

Nya. Tatyasaheb Athalye Arts, Ved. S. R. Sapre Commerce and Vid. Dadasaheb Pitre Science College, Devrukh (An Autonomous College Affiliated with University of Mumbai)

1. S.M. Sze; Semiconductor Devices: Physics and Technology, 2nd edition, John Wiley, New York, 2002.
2. B.G. Streetman and S. Benerjee; Solid State Electronic Devices, 5th edition, Prentice Hall of India, NJ, 2000.
3. W.R. Runyan; Semiconductor Measurements and Instrumentation, McGraw Hill, Tokyo, 1975.
4. Adir Bar-Lev; Semiconductors and Electronic devices, 2nd edition, Prentice Hall, Englewood Cliffs, N.J., 1984.
5. Jasprit Singh; Semiconductor Devices: Basic Principles, John Wiley, New York, 2001.
6. Donald A. Neamen; Semiconductor Physics and Devices: Basic Principles, 3rd edition, Tata McGraw-Hill, New Delhi, 2002.
7. M. Shur; Physics of Semiconductor Devices, Prentice Hall of India, New Delhi, 1995.
8. Pallab Bhattacharya; Semiconductor Optoelectronic Devices, Prentice Hall of India, New Delhi, 1995.
9. S.M. Sze; Physics of Semiconductor Devices, 2nd edition, Wiley Eastern Ltd., New Delhi, 1985.

Access to the Course

The course is available for all the students admitted for Master of Science in Physics.

Methods of Assessment

The assessment pattern would be 60:40, 60% for Semester End Examination (SEE) and 40% for Continuous Internal Assessment (CIA). The structure of the SEE and CIA would be as recommended by the Board of Studies and approved by the Board of Examination and the Academic Council of the college.

Pattern of Evaluation

The Examination/Evaluation pattern shall be framed by the Board of Examination with its final approval from the Academic Council of the College.